

Features

- Resolution: 8-Bit ± 0.5 LSB(DNL)
- Maximum Conversion Rate: 20 MSPS
- Built-in Sample and Hold Function
- Built-in Reference Voltage Self Bias Circuit
- Single +5.0 V Power Supply
- Three-State TTL Compatible Output
- Direct Replacement for the Sony CXD1175

Applications

- Video Digitizing
- Personal Computer Video
- Multimedia
- Digital Television

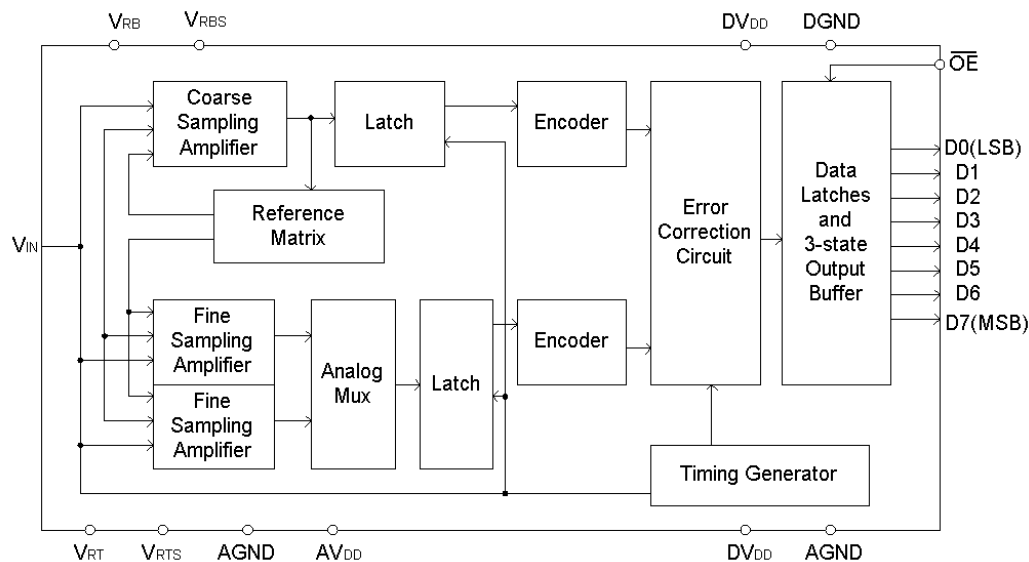
General Description

The AT1175 is a CMOS two-step A/D converter capable of digitizing full-scale analog input signals into 8-bit digital words at sample rate of 20 MSPS.

For most application, no external sample-and-hold or video driving amplifiers are needed thanks to the device's narrow aperture time, wide bandwidth, and low input capacitance.

The AT1175 operates from a single +5.0V power supply and has an internal voltage reference, which eliminates the need for external reference circuitry. All digital inputs are CMOS compatible and the tri-state outputs are TTL-compatible. The AT1175 is ideal for most video and image processing applications that require low power dissipation and low cost.

Block Diagram



Aimtron reserves the right without notice to change this circuitry and specifications.

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Absolute Maximum Ratings (Beyond which damage may occur) 25°C

Supply Voltages	Temperature
V _{DD}-0.5 to +7.0 V	Operating Temperature-20 to +70°C
Input Voltages	Junction Temperature175°C
Analog InputAGND to V _{DD}	Lead Temperature, (Soldering 10 seconds)300°C
Reference Input VoltageAGND to V _{DD}	Storage Temperature-55 to +125°C
ESD Susceptibility±1,500V	

Electrical Specifications

T_a=+25°C, AV_{DD}=DV_{DD}=V_{DD}=+5.0V, AGND=DGND=0.0V, V_{RB}=1V and V_{RT}=3V, fs=20 MSPS ,unless otherwise specified.

PARAMETERS	TEST CONDICTION	MIN	TYP	MAX	UNITS
Resolution		8			Bits
DC Accuracy (+25°C)					
Integral Nonlinearity	fs=20 MSPS,		±0.8		LSB
Differential Nonlinearity	V _{IN} =1.0V to 3.0V		±0.5		LSB
Zero Scale Error	EZS	-10	-35	-60	mV
Full Scale Error	EFS	0	45	60	mV
No Missing Codes			Guaranteed		
Analog Input					
Input Voltage Range	V _{IN}	V _{RB}		V _{RT}	V
Input Bias Current				±5.0	μA
Input Resistance		100	200		kΩ
Input Capacitance			15		pF
Reference Input					
Reference Ladder Resistance	V _{RT} to V _{RB}	200	270	340	Ω
Reference Current	V _{RT} - V _{RB} =2.0V	5.2	7.5	10.5	mA
Reference Input Voltage	V _{RB}	0.0	0.6	3.0	V
	V _{RT}	2.0	2.6	V _{DD}	V
Reference Differential	V _{RT} - V _{RB}	1.0	-	5.0	V
Internal Bias1	V _{RB}	0.55	0.60	0.65	V
	V _{RT} -V _{RB}	1.9	2.0	2.1	V
	Short V _{RT} and V _{RTS}				
	Short V _{RB} and V _{RBS}				
Internal Bias2 (V _{RT})	Short V _{RT} and V _{RTS}	2.25	2.39	2.53	V
	Short V _{RB} and AGND				
Dynamic Performance					
Signal-To-Noise Ratio	fs=14.29 MSPS				
fin=1.667MHz		44	46		dB
fin=3.85MHz		43			dB
Spurious Free Dynamic Range	fs=14.29 MSPS				
fin=1.667MHz		43	48		dB
fin=3.85MHz		41	42		dB
Differential Phase	NTSC 40 IRE Mod Ramp		0.7		Degrees
Differential Gain	fs=14.3 MSPS		1.0		%
Digital Inputs					
Voltage, Logic High		4.0		V _{DD}	V

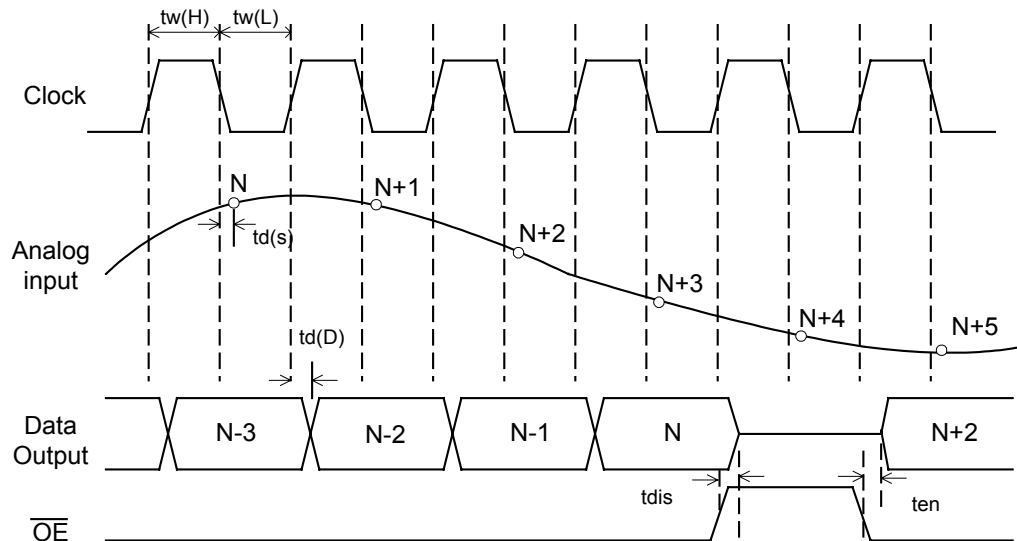
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Voltage, Logic Low		0	1.0	V	
Input Current, Logic High	$V_{DD}=\max, V_{IH}=V_{DD}$		5.0	μA	
Input Current, Logic Low	$V_{DD}=\max, V_{IL}=\text{DGND}$		5.0	μA	
Digital Outputs					
Output Current, Logic High	$V_{DD}=\min \quad V_{OH}=4.25V$	- 1.1		mA	
Output Current, Logic Low	$V_{DD}=\min \quad V_{OL}=0.4V$	2.0		mA	
Output Current, High 'Z'	$V_{DD}=\max \quad /OE=V_{DD}$		± 1	μA	
Voltage , Logic High	$I_{OH}=-4mA$	3.5		V	
Voltage , Logic Low	$I_{OL}=-4mA$		0.8	V	
Power Supply Requirements					
AV_{DD} (Analog Supply Voltage)		+4.75	+5.0	+5.25	V
DV_{DD} (Digital Supply Voltage)		+4.75	+5.0	+5.25	V
Supply Voltage Difference	$(AV_{DD}-DV_{DD})$	-0.1	0.0	0.1	V
Supply Current	$f_s=20 \text{ MSPS}$ (Does not include ref. current)		30		mA
Power Dissipation	NTSC ramp wave input		150		mW

Timing Specifications

$T_a=+25^\circ C, AV_{DD}=DV_{DD}=V_{DD}=+5.0V, AGND=DGND=0.0V, V_{RB}=1V$ and $V_{RT}=3V, f_s=20 \text{ MSPS}$, unless otherwise specified.

PARAMETERS	TEST CONDICTION	MIN	TYP	MAX	UNITS
f_s Maximum conversion rate	$f_{in}=1 \text{ kHz ramp}$	20			MSPS
$t_{w(H)}$ Pulse Width High		15			ns
$t_{w(L)}$ Pulse Width Low		15			ns
$t_{d(D)}$ Digital output delay time	$C_L \leq 10pF$		18	30	ns
t_{AJ} Aperture jitter time			30		ps
$t_{d(S)}$ Sampling delay time			4		ns
t_{en} Output Enable time	$C_L=10pF$		5		ns
t_{dis} Output Disable time	$C_L=10pF$		7		ns



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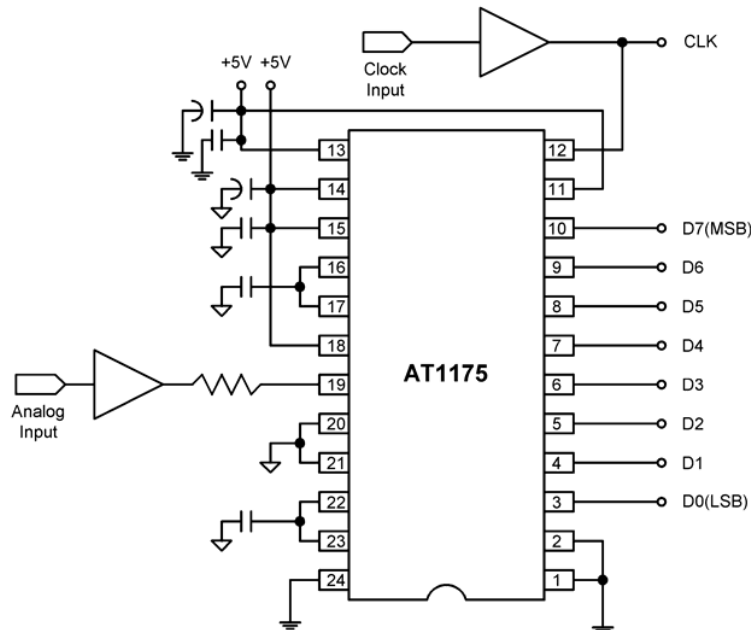
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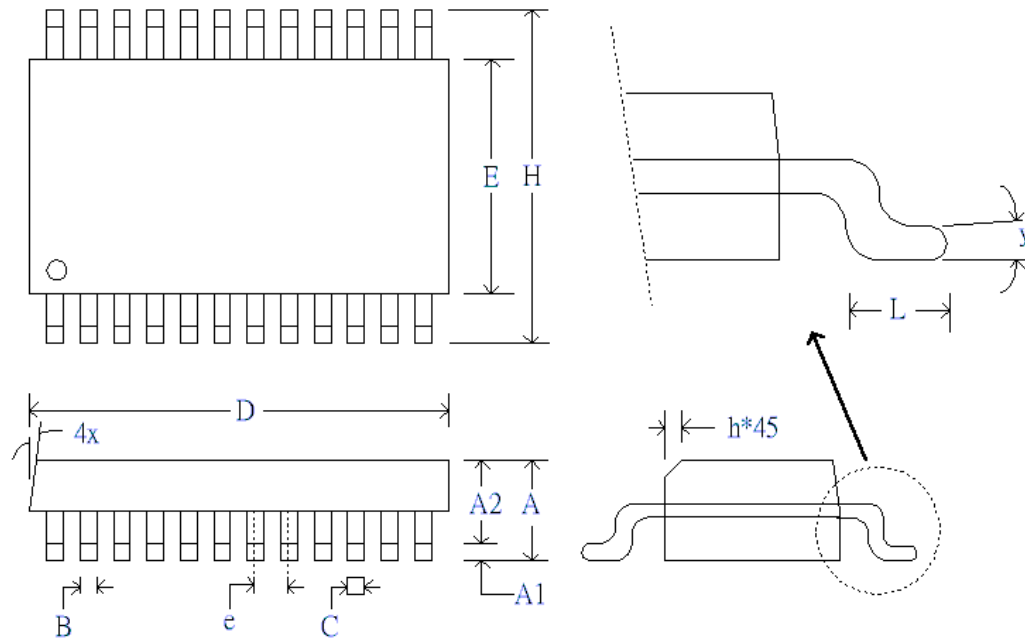
Digital Output Code

Input Signal Voltage	Step	Digital output code							
		MSB				LSB			
V_{RT}	0	1	1	1	1	1	1	1	1
.	.	1	1	1	1	1	1	1	0
.
.	127	1	0	0	0	0	0	0	0
.	128	0	1	1	1	1	1	1	1
.
.	254	0	0	0	0	0	0	0	1
V_{RB}	255	0	0	0	0	0	0	0	0

Typical Application Schematic



Package Outline (24-pin 300 mil Plastic SOP)



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	2.36	2.49	2.64	0.093	0.098	0.104
A1	0.10	-	0.30	0.004	-	0.012
A2	-	2.34	-	-	0.092	-
B	0.33	0.41	0.51	0.013	0.016	0.020
C	0.23	0.25	0.33	0.009	0.010	0.012
D	15.19	15.39	15.49	0.598	0.606	0.610
E	7.39	7.49	7.59	0.291	0.295	0.299
e	-	1.27	-	-	0.050	-
H	10.01	10.31	10.64	0.394	0.406	0.419
L	0.38	0.81	1.27	0.015	0.032	0.050
y	0	-	8	0	-	8

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